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<u>Diodes Incorporated</u> <u>ZXTN620MATA</u>

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Datasheet of ZXTN620MATA - TRANS NPN 80V 3.5A 3-DFN

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# A Product Line of Diodes Incorporated



ZXTN620MA

#### **80V NPN LOW SATURATION TRANSISTOR**

#### **Features and Benefits**

- BV<sub>CEO</sub> > 80V
- I<sub>C</sub> = 3.5A Continuous Collector Current
- Low Saturation Voltage (185mV max @ 1A)
- R<sub>SAT</sub> = 68 mΩ for a low equivalent On-Resistance
- hFE specified up to 5A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R<sub>θJA</sub> efficient, 60% lower than SOT23
- 4mm² footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

#### **Applications**

- MOSFET Gate Driving
- DC–DC Converters
- Charging circuitsMotor Control
- 101010100111101
- Power switches

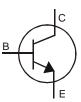
#### DFN2020B-3



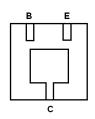




**Bottom View** 



Device Symbol



Bottom View Pin-Out

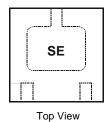
#### **Ordering Information**

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN620MATA	SE	7	8	3000

Notes:

- 1. No purposefully added lead.
- Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

### **Marking Information**



SE = Product Type Marking code



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# **Maximum Ratings** @ $T_A = 25^{\circ}C$ unless otherwise specified

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		$V_{CBO}$	100		
Collector-Emitter Voltage		V <sub>CEO</sub>	80	V	
Emitter-Base Voltage		V <sub>EBO</sub>	7		
Peak Pulse Current		Ісм	5		
Continuous Collector Current	(Note 3)	I.	3.5	۸ .	
	(Note 4)	- Ic	3.8		
Base Current		I <sub>B</sub>	1		

### Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)		1.5 12	W	
Linear Derating Factor	(Note 4)	PD	2.45 19.6	mW/°C	
Thermal Desistance Investiga to Ambient	(Note 3)	-	83	°C/W	
Thermal Resistance, Junction to Ambient	(Note 4)	$R_{\theta JA}$	51		
Thermal Resistance, Junction to Lead (Note 5)		$R_{ hetaJL}$	16.8		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

Notes:

- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.

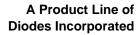
  4. Same as note (3), except the device is measured at t ≤ 5 sec.

  5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

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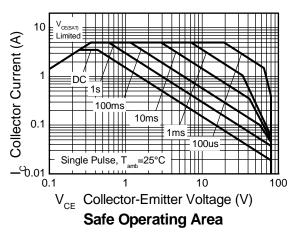


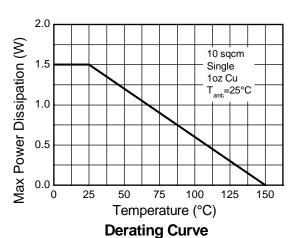


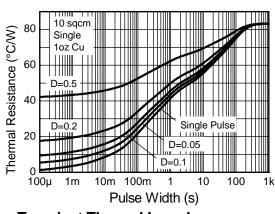


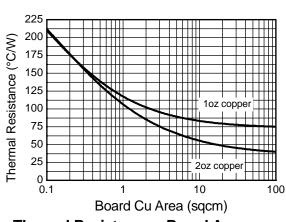
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#### **Thermal Characteristics**



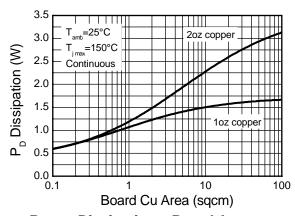






#### **Transient Thermal Impedance**

Thermal Resistance v Board Area



**Power Dissipation v Board Area** 



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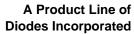
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#### Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	100	180	-	٧	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV <sub>CEO</sub>	80	110	-	٧	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.2	-	V	I <sub>E</sub> = 100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 80V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	. nA	$V_{EB} = 6V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CE</sub> = 65V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200 300 110 60 20	450 450 170 90 30 10	- 900 - - - -	-	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V I <sub>C</sub> = 200mA, V <sub>CE</sub> = 2V I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V I <sub>C</sub> = 1.5A, V <sub>CE</sub> = 2V I <sub>C</sub> = 3A, V <sub>CE</sub> = 2V I <sub>C</sub> = 5A, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	- - - -	15 45 145 160 240	20 60 185 200 340	mV	$\begin{split} &I_C = 0.1 \text{A}, \ I_B = 10 \text{mA} \\ &I_C = 0.5 \text{A}, \ I_B = 50 \text{mA} \\ &I_C = 1 \text{A}, \ I_B = 20 \text{mA} \\ &I_C = 1.5 \text{A}, \ I_B = 50 \text{mA} \\ &I_C = 3.5 \text{A}, \ I_B = 300 \text{mA} \end{split}$
Base-Emitter Turn-On Voltage (Note 6)	$V_{BE(on)}$	-	0.96	1.05	٧	$I_C = 3.5A, V_{CE} = 2V$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	1.09	1.175	V	$I_C = 3.5A$ , $I_B = 300mA$
Output Capacitance	C <sub>obo</sub>	-	11.5	18	pF	V <sub>CB</sub> = 10V. f = 1MHz
Transition Frequency	fτ	100	160	-	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	86	-	ns	$V_{CC} = 10V, I_C = 1A$
Turn-Off Time	t <sub>off</sub>	-	1128	-	ns	$I_{B1} = I_{B2} = 25 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

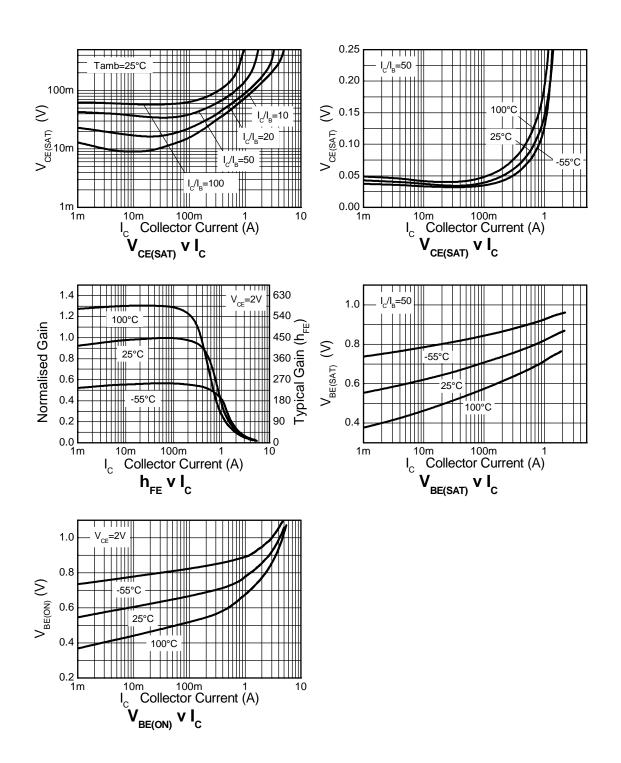






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### **Typical Electrical Characteristics**



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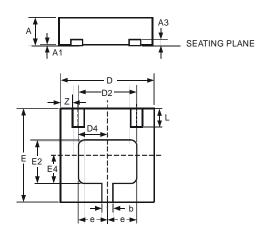






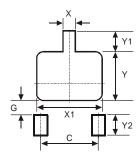
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# **Package Outline Dimensions**



DFN2020B-3					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
А3		_	0.152		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
е		_	0.65		
Е	1.95	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
L	0.25	0.35	0.30		
Z	_	_	0.225		
All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)
С	1.30
G	0.24
Х	0.35
X1	1.52
Y	1.09
Y1	0.47
Y2	0.50



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